

GT60J323H

Current Resonance Inverter Switching Application
 Induction Heating Cooking Appliances
 Induction Heating Appliances

- Enhancement mode type
- High speed : $t_f = 0.12 \mu s$ (typ.) ($I_C = 60A$)
- Low saturation voltage: $V_{CE(sat)} = 2.1 V$ (typ.) ($I_C = 60A$)
- FRD included between emitter and collector
- Fourth generation IGBT
- TO-3P(LH) (Toshiba package name)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-emitter voltage	V_{CES}	600	V
Gate-emitter voltage	V_{GES}	± 25	V
Continuous collector current	@ Tc = 100°C	30	A
	@ Tc = 25°C	60	
Pulsed collector current	I_{CP}	120	A
Diode forward current	DC	I_F	A
	Pulsed	I_{FP}	
Collector power dissipation	@ Tc = 100°C	68	W
	@ Tc = 25°C	170	
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55 to 150	°C

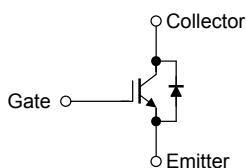
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

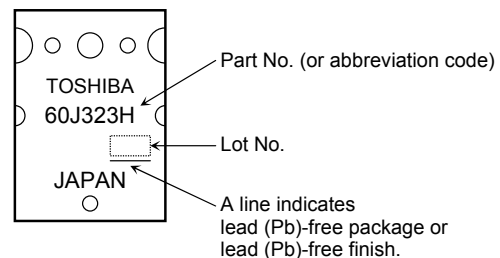
Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance (IGBT)	$R_{th(j-c)}$	0.74	°C/W
Thermal resistance (diode)	$R_{th(j-c)}$	1.56	°C/W

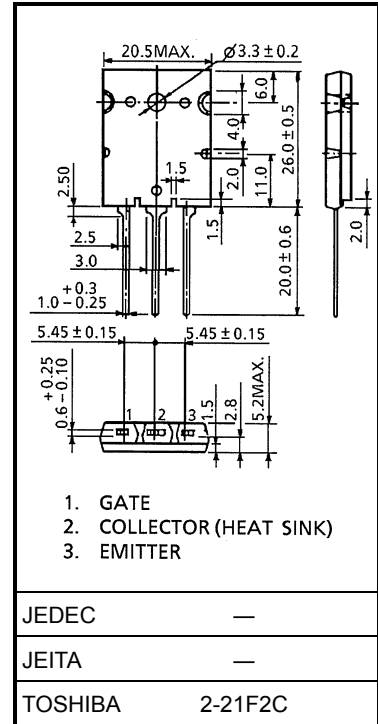
Equivalent Circuit



Marking



Unit: mm

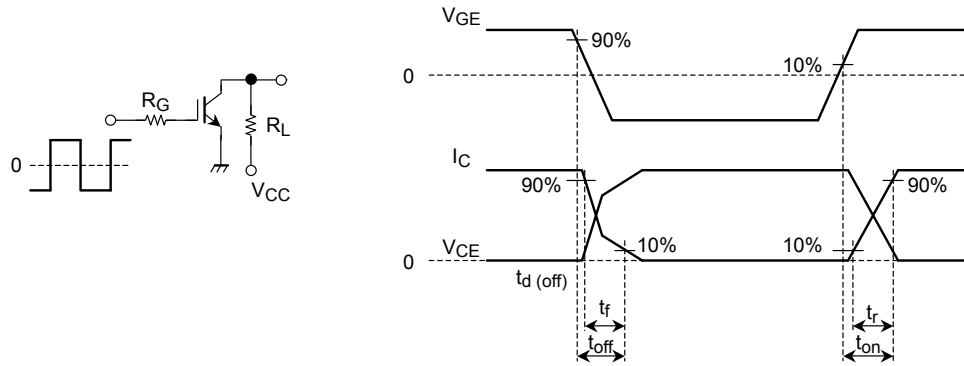


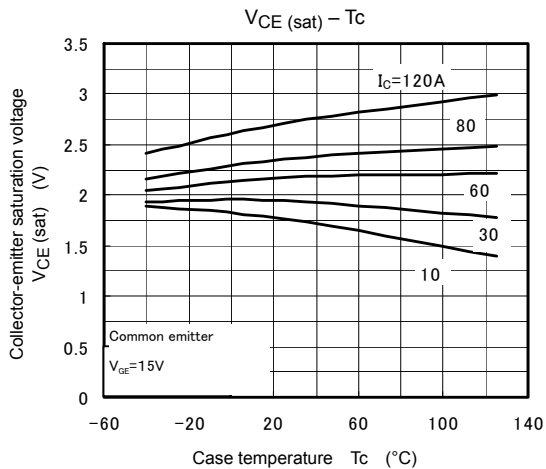
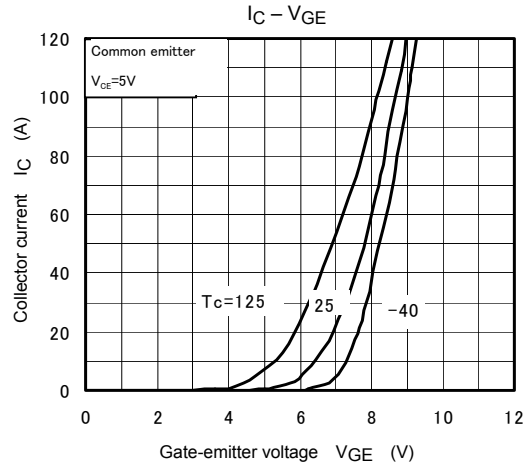
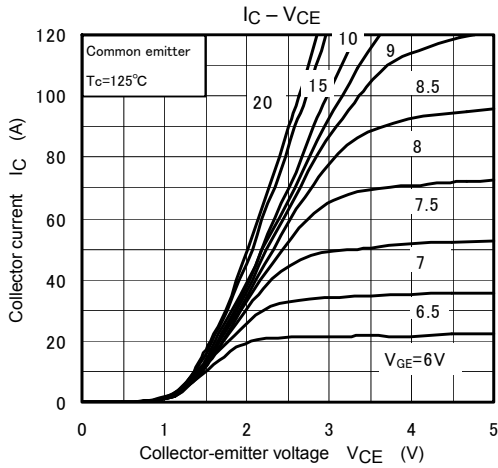
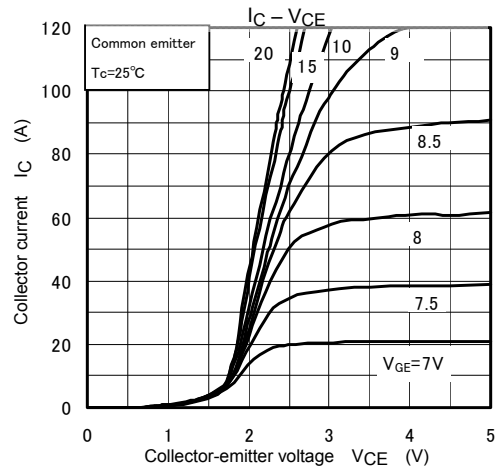
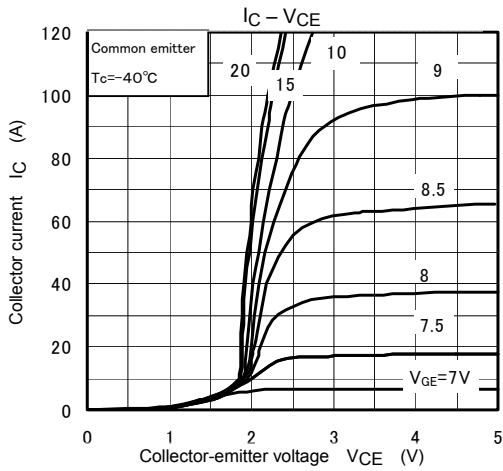
Weight: 9.75 g (typ.)

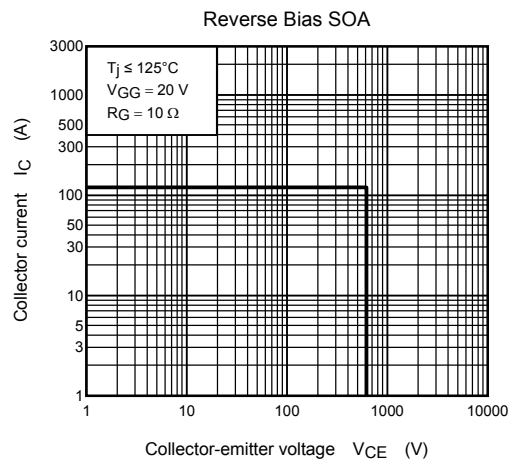
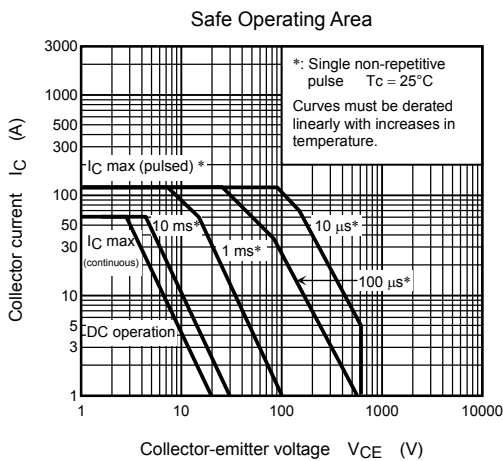
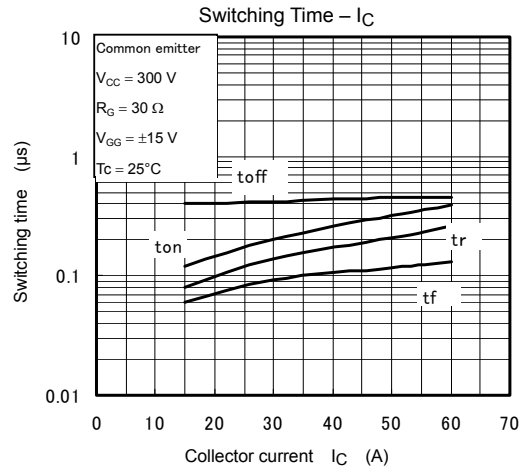
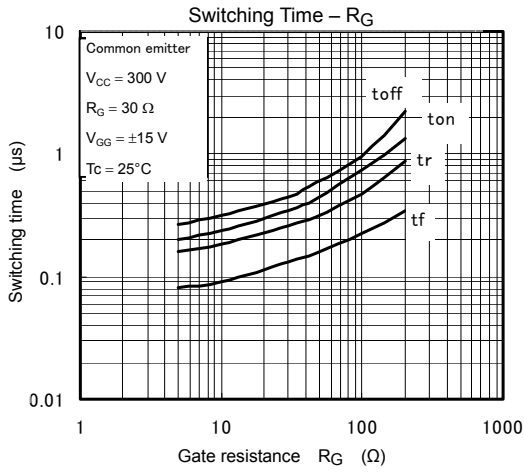
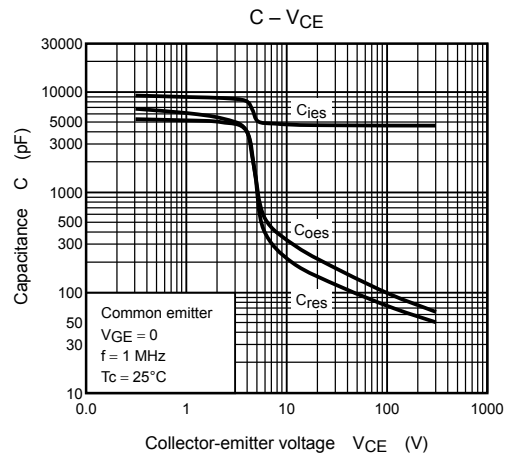
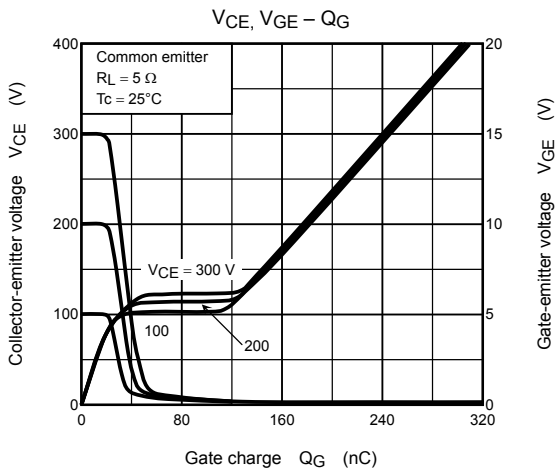
Electrical Characteristics (Ta = 25°C)

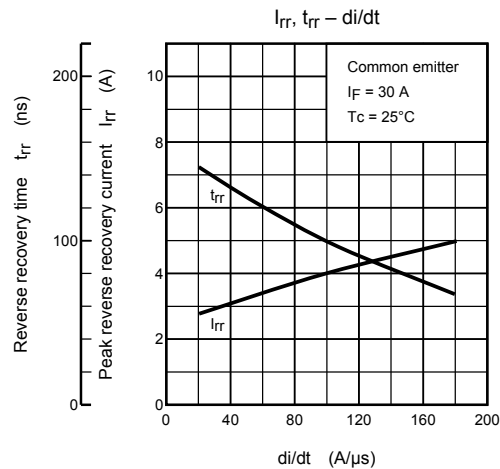
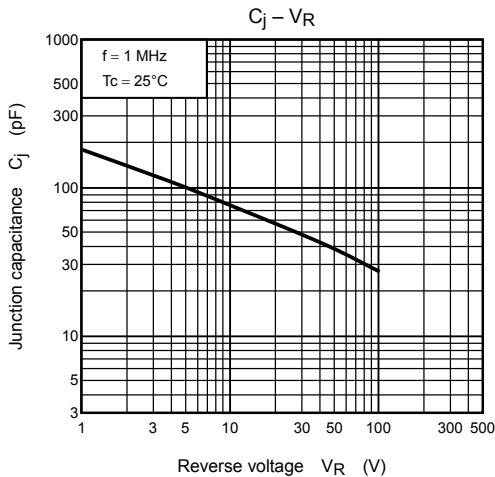
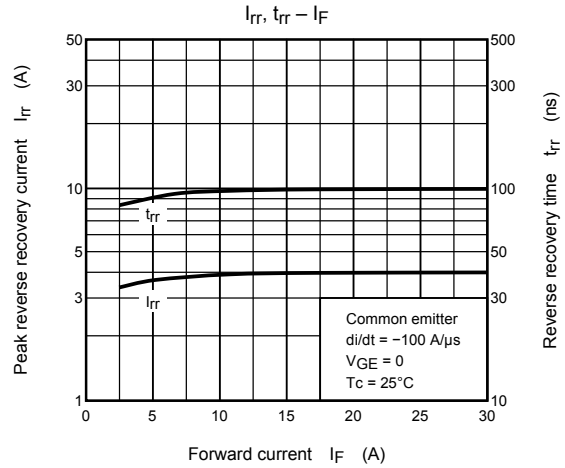
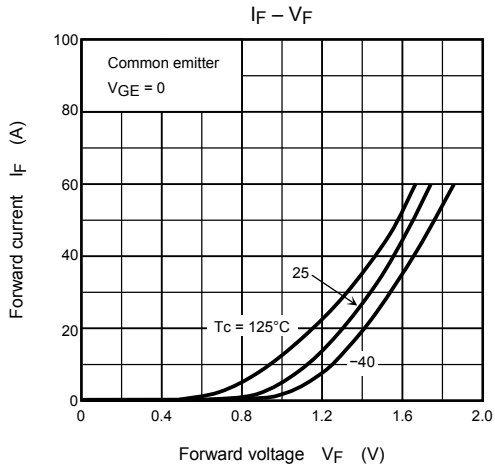
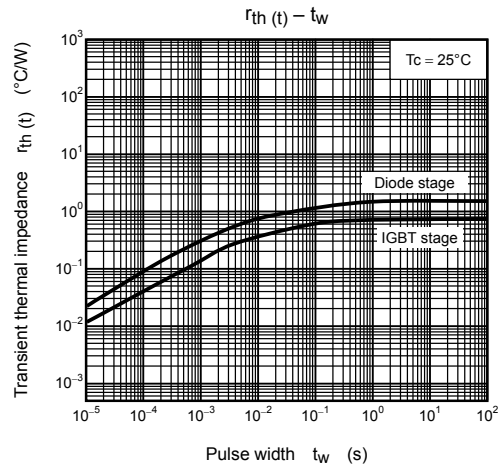
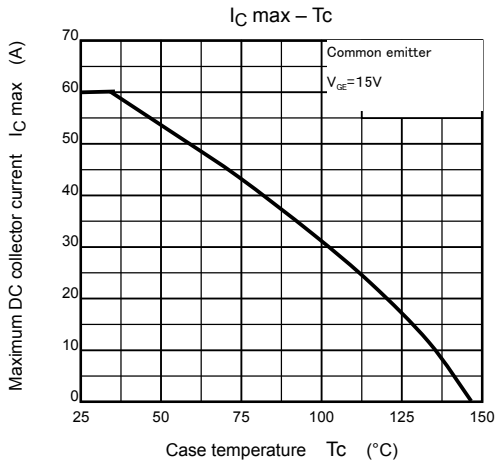
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	$V_{GE} = \pm 25 \text{ V}, V_{CE} = 0$	—	—	± 500	nA
Collector cut-off current		I_{CES}	$V_{CE} = 600 \text{ V}, V_{GE} = 0$	—	—	1.0	mA
Gate-emitter cut-off voltage		$V_{GE(OFF)}$	$I_C = 60 \text{ mA}, V_{CE} = 5 \text{ V}$	3.0	—	6.0	V
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 60 \text{ A}, V_{GE} = 15 \text{ V}$	—	2.1	2.9	V
Input capacitance		C_{ies}	$V_{CE} = 10 \text{ V}, V_{GE} = 0, f = 1 \text{ MHz}$	—	4800	—	pF
Switching time	Rise time	t_r	Resistive Load $V_{CC} = 300 \text{ V}, I_C = 60 \text{ A}$ $V_{GG} = \pm 15 \text{ V}, R_G = 30 \Omega$ (Note 1)	—	0.26	—	μs
	Turn-on time	t_{on}		—	0.39	—	
	Fall time	t_f		—	0.12	0.21	
	Turn-off time	t_{off}		—	0.41	—	
Diode forward voltage		V_F	$I_F = 30 \text{ A}, V_{GE} = 0$	—	1.4	2.0	V
Reverse recovery time		t_{rr}	$I_F = 30 \text{ A}, di/dt = -100 \text{ A}/\mu\text{s}$	—	0.1	0.2	μs

Note 1: Switching time measurement circuit and input/output waveforms









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